EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L2	2	((active near3 matrix) TFT.u/c. (thin near3 film near3 transistor)) with (EL.u/c. electro $1luminescen$ lumines$6) with ((well near3 known) conventional $4) and (x$electrode (x near3 electrode)) same parallel	US-PGPUB; USPAT; USOCR	OR	ON	2008/04/22 13:08
S1	92	(((sulfide selenide telluride nitride phosphide arsenide antimonide carbide oxide chloride bromide iodide) with (cadmium zinc mercury lead tin indium antimony arsenic silicon gallium aluminum bismuth beryllium magnesium calcium strontium)) sulfur selenium tellurium silicon germanium) with (particle) same (cover $4 coat$4 embed$5 dispers$5) same ((poly Nvinylcarbazole) PVK (polyethylene near3 dioxythiophene) PEDOT (polystyrene near3 sulfonic near3 acid) PSS (polymethyl near3 phenylsilane) PMPS)	US-PGPUB; USPAT; USOCR	OR	ON	2008/04/22 10:24
S2	2707	(n$type semiconductor) with (transistor TFT.u/c. (thin near3 film near3 transistor)) same (EL. u/c. electro $1luminescen$ lumines$6)	US-PGPUB; USPAT; USOCR	OR	ON	2008/04/22 10:40
S3	1649	(313/503).CCLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2008/04/22 10:40

S4	4935	(313/504).CCLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2008/04/22 10:40
S5	760	(313/498).CCLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2008/04/22 10:41
S6	2573	(428/141).CCLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2008/04/22 10:41
S7	1685	(428/216).CCLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2008/04/22 10:42
S8	1615	(313/512).CCLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2008/04/22 10:42
S9	328	(313/501).CCLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2008/04/22 10:42
S10	1447	(n$type semiconductor) with (transistor TFT.u/c. (thin near3 film near3 transistor)) with (EL.u/c. electro$1luminescen$ lumines$6)	US-PGPUB; USPAT; USOCR	OR	ON	2008/04/22 10:47
S11	1	("4937150").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2008/04/22 10:54
S12	794	((active near3 matrix) TFT.u/c. (thin near3 film near3 transistor)) with (EL.u/c. electro $1luminescen$ lumines $6) with ((well near3 known) conventional $4)	US-PGPUB; USPAT; USOCR	OR	ON	2008/04/22 11:01
S13	794	((active near3 matrix) TFT.u/c. (thin near3 film near3 transistor)) with (EL.u/c. electro $1luminescen$ lumines $6) with ((well near3 known) conventional $4)	US-PGPUB; USPAT; USOCR	OR	ON	2008/04/22 11:03
S14	4	((active near3 matrix) TFT.u/c. (thin near3 film near3 transistor)) with (EL.u/c. electro $1luminescen$ lumines $6) with (inorganic) with ((well near3 known) conventional $4)	US-PGPUB; USPAT; USOCR	OR	ON	2008/04/22 11:03
S15	2	"08306485"	EPO; JPO; DERWENT	OR	ON	2008/04/22 11:05

S16	1	"6366282"	EPO; JPO; DERWENT	OR	ON	2008/04/22 11:05
S17	2	"63066282"	EPO; JPO; DERWENT	OR	ON	2008/04/22 11:06
S18	2	"63318092"	EPO; JPO; DERWENT	OR	ON	2008/04/22 11:06
S19	2	"2002299063"	EPO; JPO; DERWENT	OR	ON	2008/04/22 11:06
S20	2	"2003115385"	EPO; JPO; DERWENT	OR	ON	2008/04/22 11:06

4/22/2008 1:10:50 PM
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